

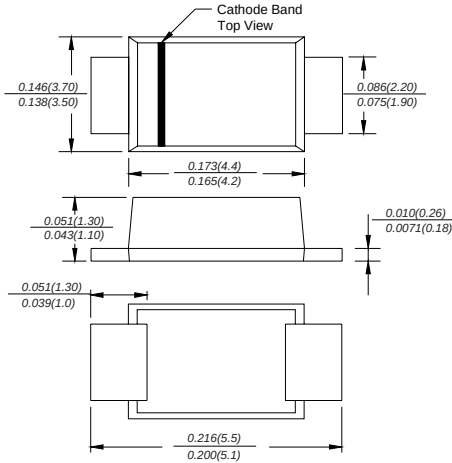


SS52BF THRU SS520BF

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts Forward Current - 5.0 Ampere

SMBF



Dimensions in inches and (millimeters)

FEATURES

- ◆ Metal silicon junction, majority carrier conduction
- ◆ For surface mounted applications
- ◆ Low power loss, high efficiency
- ◆ High forward surge current capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

Case: JEDEC SMBF molded plastic body

Terminals: leads solderable per MIL-STD-750, Method 2026

Mounting Position: Any

Weight: 57mg/0.002oz

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS52BF	SS54BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF	UNITS
Marking code		S52B	S54B	S56B	S58F	S510B	S515B	S520B	
Maximum repetitive peak reverse voltage	V_{RRM}	20	40	60	80	100	150	200	VOLTS
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V_{DC}	20	40	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T_L (see fig.1)	I_{AV}	5.0							Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0							Amps
Maximum instantaneous forward voltage at 5.0A	V_F	0.55		0.70		0.85		0.95	Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	1.0 50							mA
Typical junction capacitance (NOTE 1)	C_J	800			500				pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	40.0							$^\circ\text{C/W}$
Operating junction temperature range	T_J	-50 to +125							$^\circ\text{C}$
Storage temperature range	T_{STG}	-50 to +150							$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas



RATINGS AND CHARACTERISTIC CURVES SS52BF THRU SS520BF

Fig.1 Forward Current Derating Curve

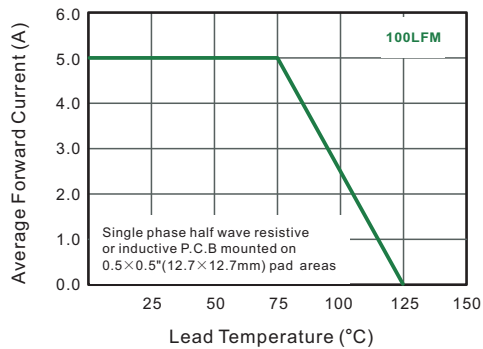


Fig.2 Typical Reverse Characteristics

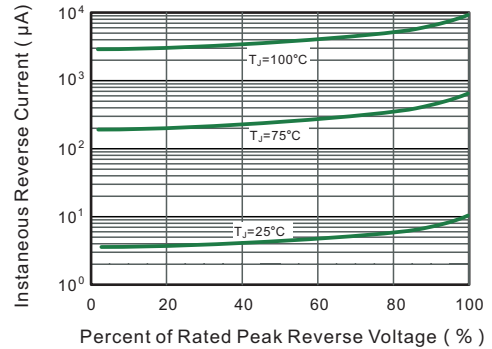


Fig.3 Typical Forward Characteristic

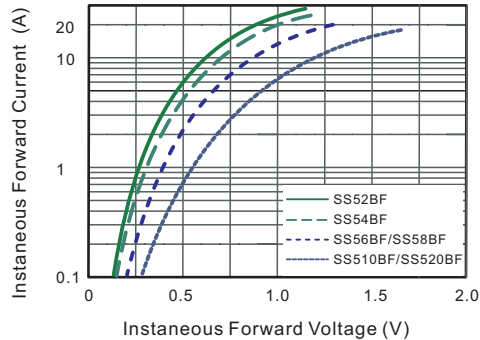


Fig.4 Typical Junction Capacitance

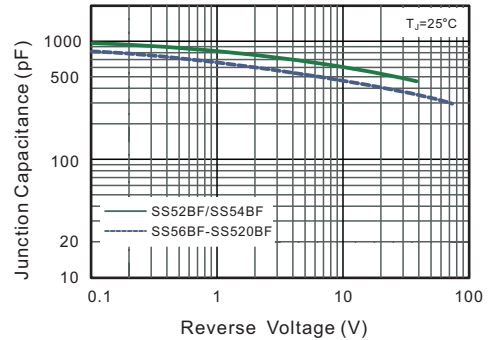


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

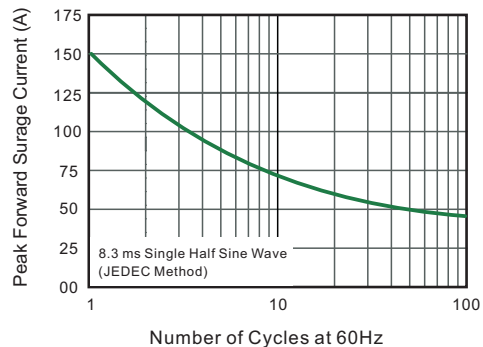
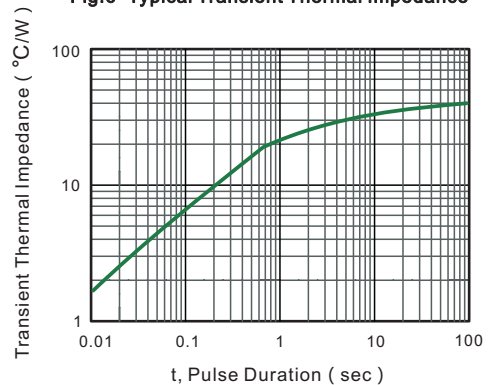


Fig.6- Typical Transient Thermal Impedance



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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